

MH254 Hall-effect sensor is a temperature stable, stress-resistant, Low Tolerance of Sensitivity micro-power switch. Superior high-temperature performance is made possible through a dynamic offset cancellation that utilizes chopper-stabilization. This method reduces the offset voltage normally caused by device over molding, temperature dependencies, and thermal stress.

MH254 is special made for low operation voltage, 1.65V, to active the chip which includes the following on a single silicon chip: voltage regulator, Hall voltage generator, small-signal amplifier, chopper stabilization, Schmitt trigger, CMOS output driver. Advanced CMOS wafer fabrication processing is used to take advantage of low-voltage requirements, component matching, very low input-offset errors, and small component geometries. This device requires the presence of unipolar magnetic fields for operation.

The package type is in a Halogen Free version has been verified by third party Lab.

### ***Features and Benefits***

- CMOS Hall IC Technology
- Strong RF noise protection
- 1.65 to 6V for battery-powered applications
- Operation down to 1.65V, Unipolar Hall Switch Micro power consumption
- High Sensitivity for reed switch replacement applications
- Low sensitivity drift in crossing of Temp. range
- Ultra Low power consumption at 5uA (Avg)
- High ESD Protection, HBM > ±4KV( min )
- Totem-pole output

### ***Applications***

- Solid state switch
- Handheld Wireless Handset Awake Switch ( Flip Cell/PHS Phone/Note Book/Flip Video Set)
- Magnet proximity sensor for reed switch replacement in low duty cycle applications
- Water Meter
- PDA
- PDVD
- NB
- Pad PC

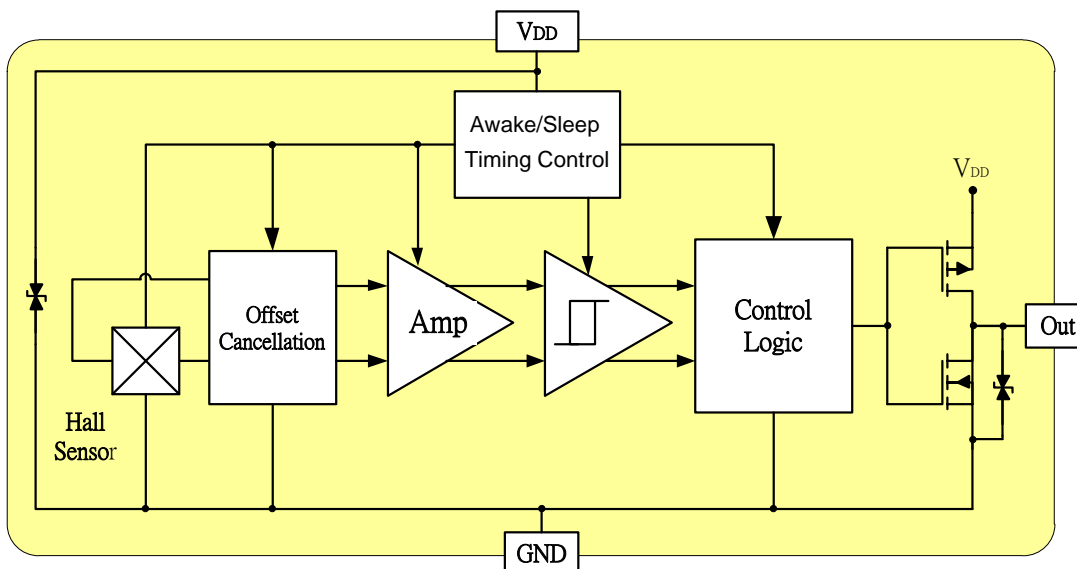
### Ordering Information

<div style="display: flex; align-items: center; gap: 10px;"> <span style="background-color: yellow; border: 1px solid black; padding: 2px 5px;">XX</span> <span style="background-color: green; border: 1px solid black; padding: 2px 5px;">XXXX</span> <span style="background-color: blue; border: 1px solid black; padding: 2px 5px;">X</span> <span style="background-color: red; border: 1px solid black; padding: 2px 5px;">XX</span> <span style="font-size: 24px;">-</span> <span style="background-color: gray; border: 1px solid black; padding: 2px 5px;">X</span> </div> <div style="margin-top: 20px;"> <p style="margin-left: 100px;">└── Sorting Code</p> <p style="margin-left: 100px;">└── Package type</p> <p style="margin-left: 100px;">└── Temperature Code</p> <p style="margin-left: 100px;">└── Part number</p> <p style="margin-left: 100px;">└── Company Name and Product Category</p> </div>	<p><b>Company Name and Product Category</b> MH:MST Hall Effect/MP:MST Power MOSFET</p> <p><b>Part number</b> 181,182,183,184,185,248,249,276,477,381,381F,381R,382..... If part # is just 3 digits, the fourth digit will be omitted.</p> <p><b>Temperature range</b> E: 85 °C, I: 105 °C, K: 125 °C, L: 150 °C</p> <p><b>Package type</b> UA:TO-92S,VK:TO-92S(4pin),VF:TO-92S(5pin),SO:SOT-23, SQ:QFN-3,ST:TSOT-23,SN:SOT-553,SF:SOT-89(5pin)</p> <p><b>Sorting</b> <math>\alpha, \beta</math>, Blank.....</p>
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Part No.	Temperature Suffix	Package Type
MH254EST	E (-40°C to + 85°C)	ST (TSOT-23)

*Custom sensitivity selection is available by MST sorting technology*

### Functional Diagram



**Note:** Static sensitive device; please observe ESD precautions. Reverse  $V_{DD}$  protection is not included. For reverse voltage protection, a 100  $\Omega$  resistor in series with  $V_{DD}$  is recommended.

**MH254, HBM >  $\pm 4KV$  which is verified by third party lab.**

#### **Absolute Maximum Ratings At( $T_a=25\text{ }^\circ\text{C}$ )**

Characteristics		Values	Unit
Supply voltage, ( $V_{DD}$ )		7	V
Output Voltage, ( $V_{out}$ )		7	V
Reverse Voltage , ( $V_{DD}$ ) ( $V_{out}$ )		-0.3	V
Magnetic flux density		Unlimited	Gauss
Output current, ( $I_{out}$ )		1	mA
Operating temperature range, ( $T_a$ )		-40 to +85	$^\circ\text{C}$
Storage temperature range, ( $T_s$ )		-65 to +150	$^\circ\text{C}$
Maximum Junction Temp, ( $T_j$ )		150	$^\circ\text{C}$
Thermal Resistance	$(\theta_{JA})$ VK / SN	227 / 540	$^\circ\text{C}/\text{W}$
	$(\theta_{JC})$ VK / SN	49 / 390	$^\circ\text{C}/\text{W}$
Package Power Dissipation, ( $P_D$ ) VK / SN		550 / 230	mW

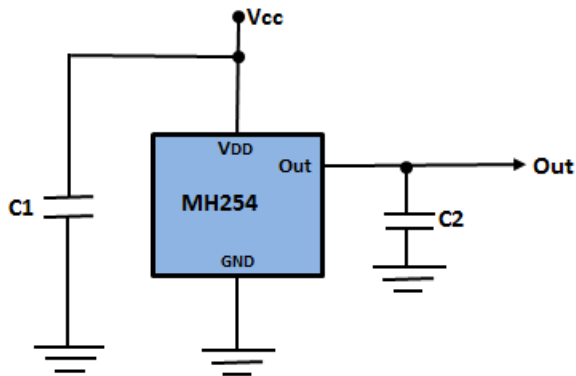
**Note:** Exceeding the absolute maximum ratings may cause permanent damage. Exposure to absolute maximum-rated conditions for extended periods may affect device reliability.

#### **Electrical Specifications**

**DC Operating Parameters** :  $T_a=25\text{ }^\circ\text{C}$ ,  $V_{DD}=1.8\text{V}$

Parameters	Test Conditions	Min	Typ	Max	Units
Supply Voltage, ( $V_{DD}$ )	Operating	1.65		6	Volts
Supply Current, ( $I_{DD}$ )	Awake State		1.4	3	mA
	Sleep State		3.6	7	$\mu\text{A}$
	Average		5	10	$\mu\text{A}$
Output Leakage	Output off			1	$\mu\text{A}$
Output High Voltage, ( $V_{OH}$ )	$I_{OUT}=0.5\text{mA}$ (Source)	$V_{DD}-0.2$			V
Output Low Voltage, ( $V_{OL}$ )	$I_{OUT}=0.5\text{mA}$ (Sink)			0.2	V
Awake mode time, ( $T_{aw}$ )	Operating		40	80	$\mu\text{S}$
Sleep mode time, ( $T_{SL}$ )	Operating		40	80	mS
Duty Cycle, ( $D, C$ )			0.1		%
Electro-Static Discharge	HBM	4			KV
Operating Point –( $B_{op}$ )	N pole to branded side, $B > B_{OP}$ , Oout On		30	50	Gauss
Release Point-( $B_{rp}$ )	N pole to branded side, $B < B_{RP}$ , Vout Off	10	20		Gauss
Hysteresis-( $B_{HYS}$ )	$ B_{OPx} - B_{RPx} $		10		Gauss

*Typical application circuit*



C1 : 10nF  
C2 : 100pF

*Sensor Location, package dimension and marking*  
MH254 Package

